



FAST RECOVERY RECTIFIER DIODES

MAIN PRODUCT CHARACTERISTICS

| | |
|----------------|-------|
| $I_{F(AV)}$ | 16 A |
| V_{RRM} | 400 V |
| $V_F(\max)$ | 1.4 V |
| $t_{rr}(\max)$ | 35 ns |

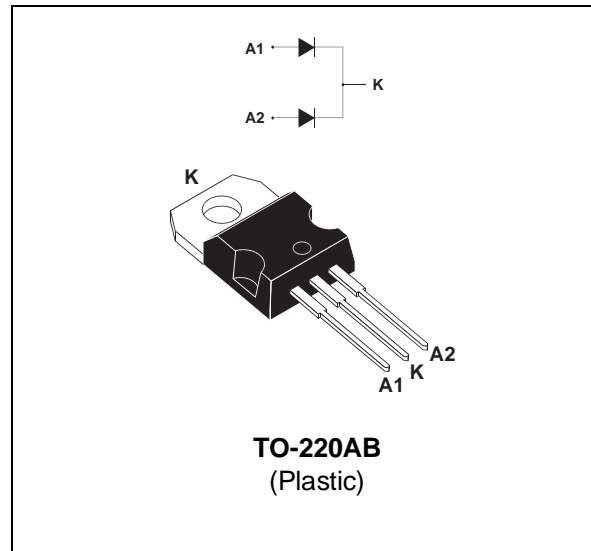
FEATURES AND BENEFITS

- VERY LOW REVERSE RECOVERY TIME
- VERY LOW SWITCHING LOSSES
- LOW NOISE TURN-OFF SWITCHING

DESCRIPTION

This double rectifier is suited for Switch Mode Power Supplies and other power converters.

This device is intended to free-wheeling function in converters and motor control circuits.



ABSOLUTE RATINGS (limiting values, per diode)

| Symbol | Parameter | Value | Unit |
|--------------|--|---------------------------------------|------------|
| V_{RRM} | Repetitive peak reverse voltage | 400 | V |
| I_{FRM} | Repetitive peak forward current | $t_p=5\ \mu s$ $F=1kHz$ | A |
| $I_{F(RMS)}$ | RMS forward current | 30 | A |
| $I_{F(AV)}$ | Average forward current | $T_c = 100^\circ C$ $\delta = 0.5$ | A |
| I_{FSM} | Surge non repetitive forward current | $t_p = 10\ ms$ Sinusoidal | A |
| T_{stg} | Storage temperature range | - 40 to + 150 | $^\circ C$ |
| T_j | Maximum operating junction temperature | 150 | $^\circ C$ |

BYT16P-400

THERMAL RESISTANCES

| Symbol | Parameter | | Value | Unit |
|---------------|------------------|-----------|-------|------|
| $R_{th(j-c)}$ | Junction to case | Per diode | 3.75 | °C/W |
| | | Total | 2 | |
| $R_{th(c)}$ | | Coupling | 0.25 | |

When the diodes 1 and 2 are used simultaneously:

$$\Delta T_{j(\text{diode } 1)} = P(\text{diode } 1) \times R_{th(j-c)} (\text{Per diode}) + P(\text{diode } 2) \times R_{th(c)}$$

STATIC ELECTRICAL CHARACTERISTICS

| Symbol | Parameter | Test Conditions | | Min. | Typ. | Max. | Unit |
|------------|-------------------------|---------------------------|--------------------|------|------|------|---------------|
| V_F^* | Forward voltage drop | $T_j = 25^\circ\text{C}$ | $I_F = 8\text{ A}$ | | | 1.5 | V |
| | | $T_j = 100^\circ\text{C}$ | | | | 1.4 | |
| I_R^{**} | Reverse leakage current | $T_j = 25^\circ\text{C}$ | $V_R = V_{RRM}$ | | | 15 | μA |
| | | $T_j = 100^\circ\text{C}$ | | | | 2.5 | mA |

Pulse test : * $t_p = 380\ \mu\text{s}$, $\delta < 2\%$

** $t_p = 5\ \text{ms}$, $\delta < 2\%$

To evaluate the conduction losses use the following equation:

$$P = 1.1 \times I_{F(AV)} + 0.024 I_{F(RMS)}^2$$

RECOVERY CHARACTERISTICS

| Symbol | Test Conditions | | Min. | Typ. | Max. | Unit |
|----------|--------------------------|---|------|------|------|------|
| t_{rr} | $T_j = 25^\circ\text{C}$ | $I_F = 1\text{ A}$ $V_R = 30\text{ V}$ $dI_F/dt = -15\text{ A}/\mu\text{s}$ | | | 75 | ns |
| | | $I_F = 0.5\text{ A}$ $I_R = 1\text{ A}$ $I_{rr} = 0.25\text{ A}$ | | | 35 | |

TURN-OFF SWITCHING CHARACTERISTICS

| Symbol | Parameter | Test Conditions | | Min. | Typ. | Max. | Unit |
|-----------------------------|----------------------------------|--------------------------------------|------------------------------|--|------|------|------|
| t_{IRM} | Maximum reverse recovery time | $dI_F/dt = -32\text{ A}/\mu\text{s}$ | $V_{CC} = 200\text{ V}$ | | | 75 | ns |
| | | $dI_F/dt = -64\text{ A}/\mu\text{s}$ | | $I_F = 8\text{ A}$ | | 50 | |
| I_{RM} | Maximum reverse recovery current | $dI_F/dt = -32\text{ A}/\mu\text{s}$ | $L_p \leq 0.05\ \mu\text{H}$ | | | 2.2 | A |
| | | $dI_F/dt = -64\text{ A}/\mu\text{s}$ | | $T_j = 100^\circ\text{C}$ (see fig. 11) | | 2.8 | |
| $C = \frac{V_{RP}}{V_{CC}}$ | Turn-off overvoltage coefficient | $T_j = 100^\circ\text{C}$ | $V_{CC} = 120\text{ V}$ | $I_F = I_{F(AV)}$ | | 3.3 | / |
| | | $dI_F/dt = -8\text{ A}/\mu\text{s}$ | $L_p = 9\ \mu\text{H}$ | (see fig. 12) | | | |

Fig. 1: Low frequency power losses versus average current.

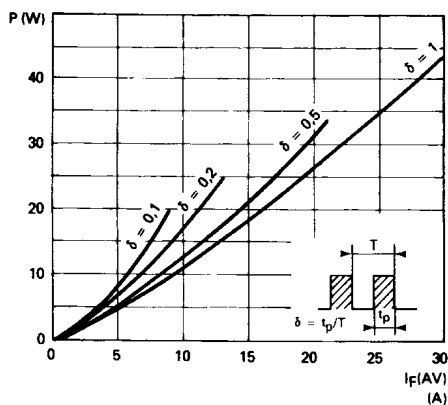


Fig. 2: Peak current versus form factor.

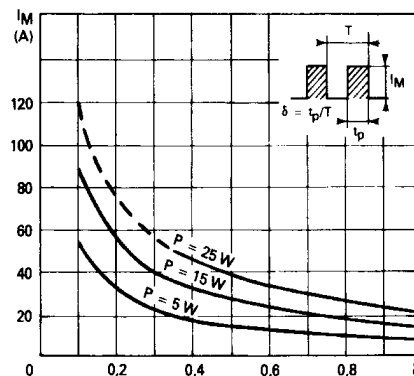


Fig. 3: Non repetitive peak surge current versus overload duration.

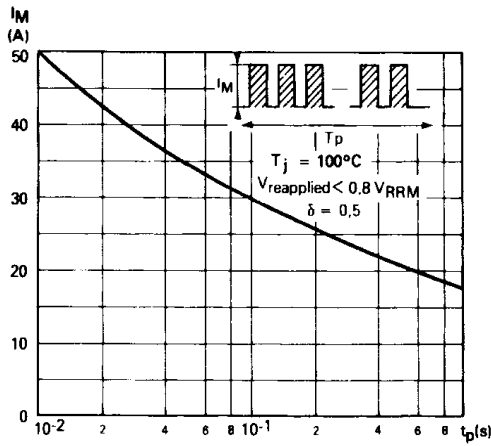


Fig. 4: Thermal impedance versus pulse width.

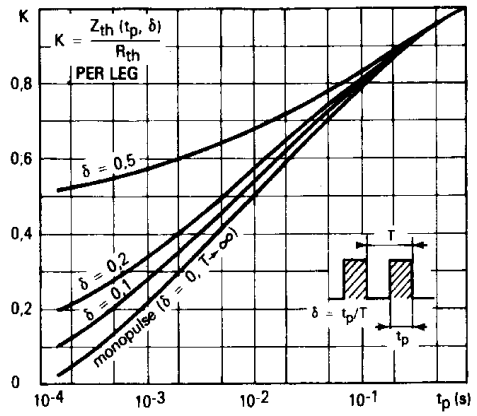


Fig. 5: Voltage drop versus forward current.

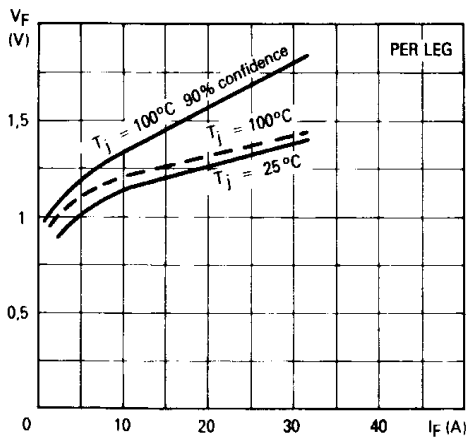


Fig. 6: Recovery charge versus di_F/dt.

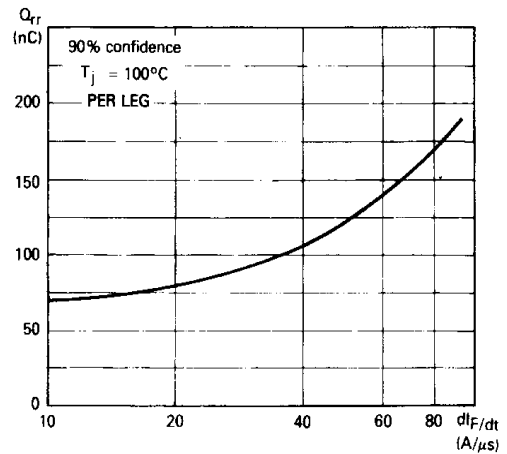


Fig. 7: Recovery time versus di_F/dt.

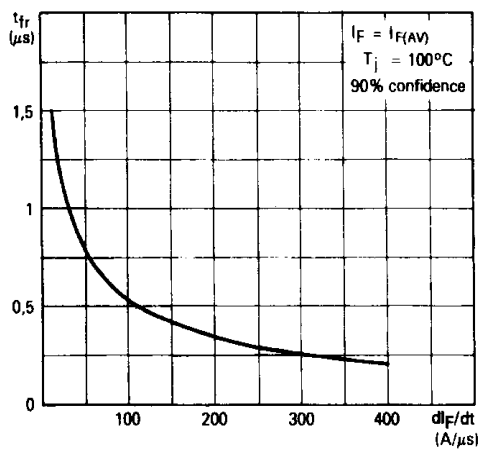


Fig. 8: Peak reverse current versus di_F/dt.

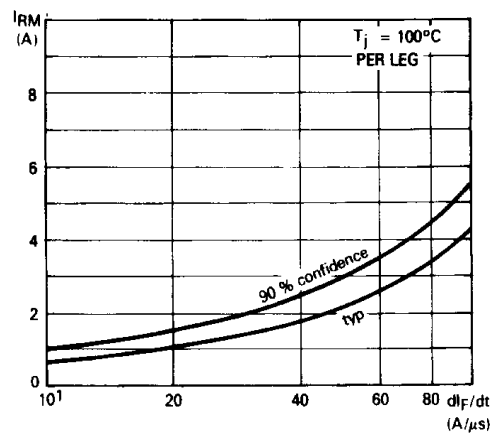


Fig. 9: Peak forward voltage versus di_F/dt .

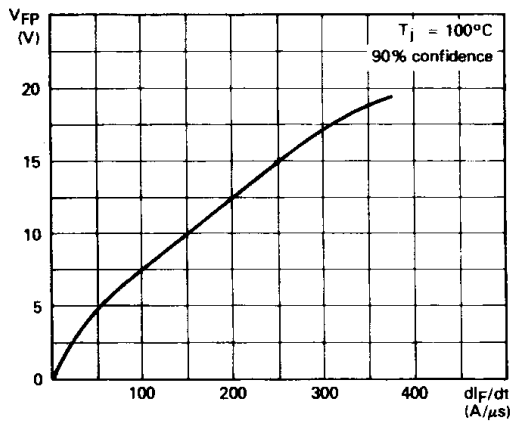


Fig. 10: Dynamic parameters versus junction temperature.

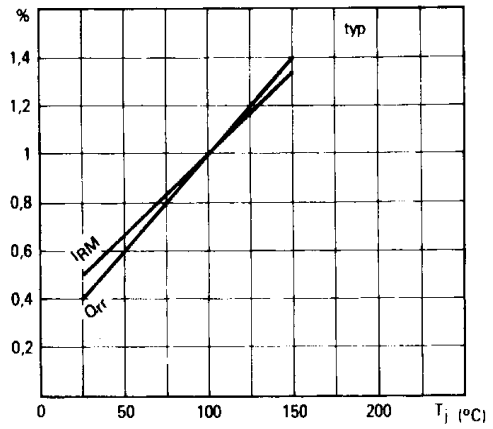


Fig. 11: Turn-off switching characteristics (without series inductance).

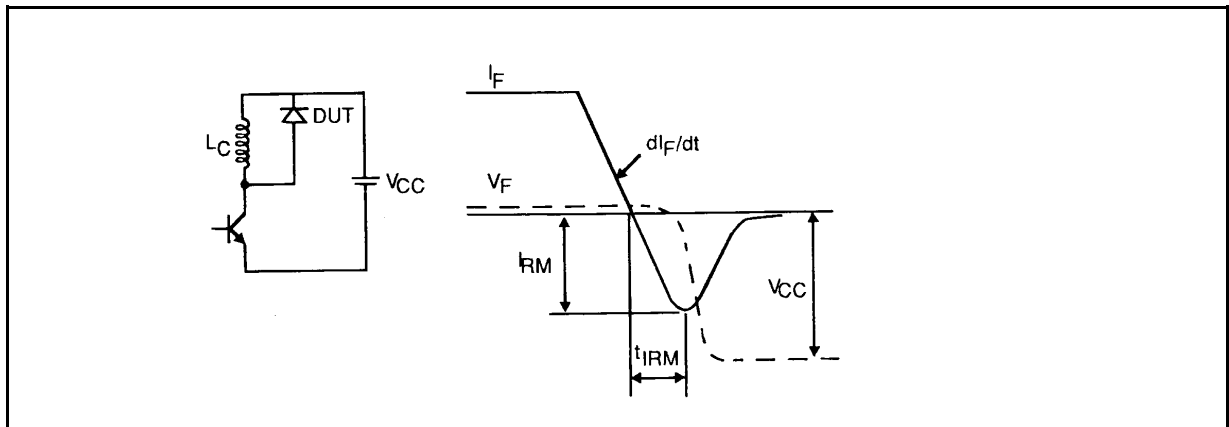
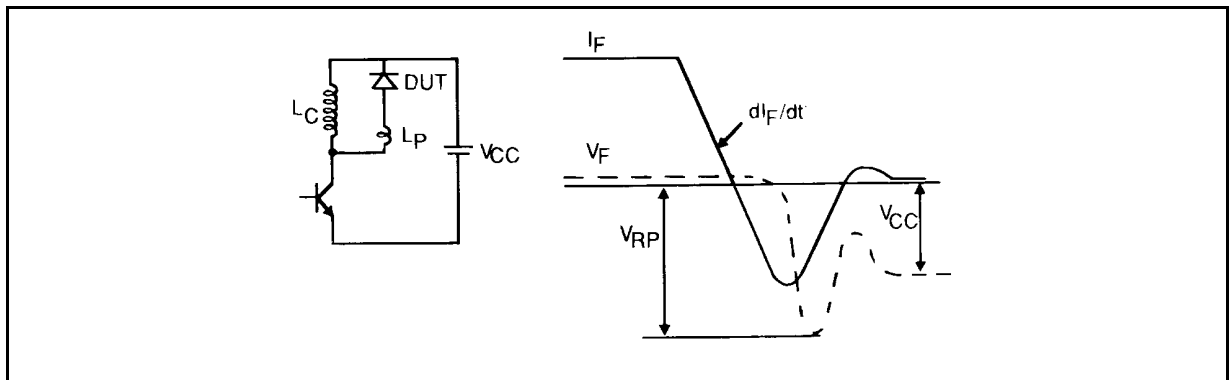
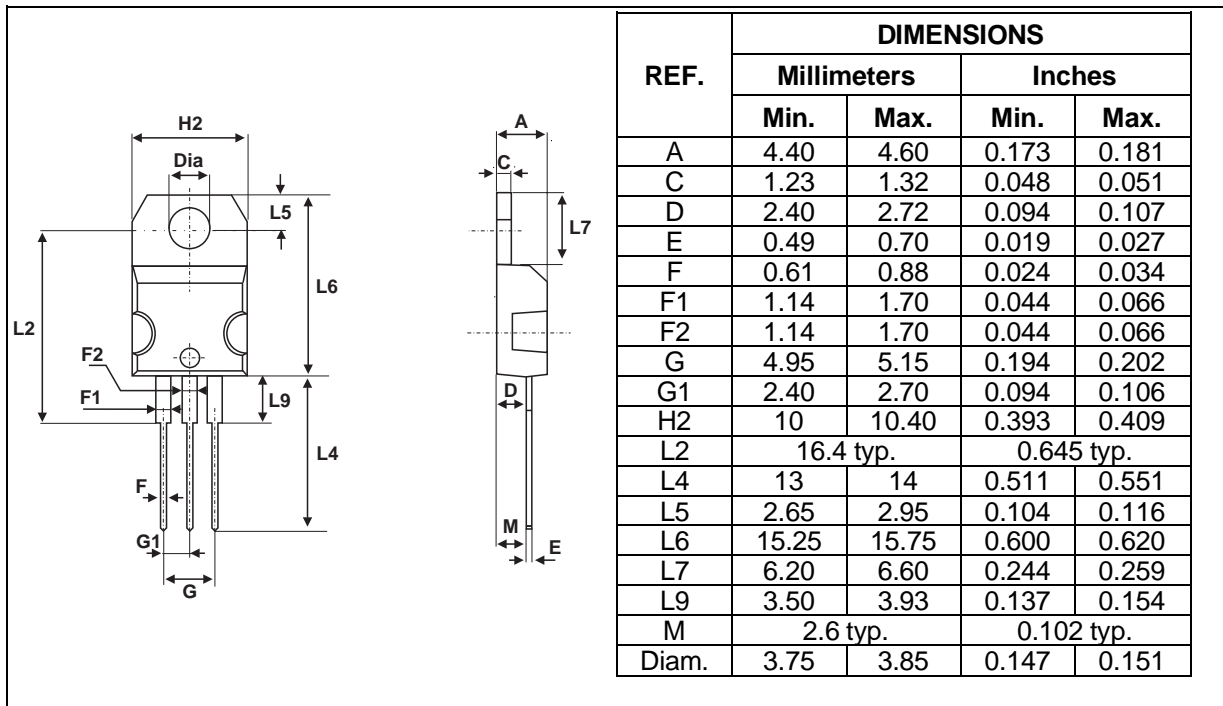


Fig. 12: Turn-off switching characteristics (with series inductance).



PACKAGE MECHANICAL DATA
 TO-220AB


| Ordering type | Marking | Package | Weight | Base qty | Delivery mode |
|---------------|------------|----------|---------|----------|---------------|
| BYT16P-400 | BYT16P-400 | TO-220AB | 2.03 g. | 30 | Tube |

- Cooling method: by conduction (C)
- Recommended torque value: 0.08 N.m.
- Maximum torque value: 0.10 N.m.
- Epoxy meets UL94,V0

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